GUJARAT TECHNOLOGICAL UNIVERSITY

NANO TECHNOLOGY (39) NANOLITHOGRAPHY SUBJECT CODE: 2183901 B.E.8th SEMESTER

Type of course: Synthesis of Nanomaterials, Thin Film Devices, Coating Technology, Characterization Technique

Prerequisite: Physics of Nanomaterials, Characterization of Nanomaterials, Coating Technology, Thin Film Technology

Rationale: To make the students understand the newly developed fabrication, physics and chemistry of multilayered devices.

Teaching and Examination Scheme:

| Teaching Scheme | | | Credits | Examination Marks | | | | | Total | |
|-----------------|---|---|---------|-------------------|--------|-----|-----------------|-----|-------|-------|
| L | T | P | C | Theory Marks | | | Practical Marks | | | Marks |
| | | | | ESE | PA (M) | | ESE (V) | | PA | |
| | | | | (E) | PA | ALA | ESE | OEP | (I) | |
| 3 | 0 | 0 | 3 | 70 | 20 | 10 | 0 | 0 | 0 | 100 |

Content:

| Sr. No. | Content | Total Hrs. | % Weightage |
|---------|---|---------------|-------------|
| 1 | PHOTORESISTS Positive and Negative Resists, Adhesion Promotion, Resist Spin Coating, Resist Soft Bake and Hard bake, Photochemistry of Resists, Acid- Catalyzed DUV Resists | 8 | 17% |
| 2 | NANOIMPRINT LITHOGRAPHY From Printing to Nano imprint, Fabrication of Mold, Separating Mold and Resists after Imprint, Residual Layer Thickness Measurement | 12 | 25% |
| 3 | X-RAY LITHOGRAPHY (XRL) Irradiation system for XRL, High Resolution and Deep XRL, Examples of X-ray lithography beamlines, Physics of X-ray lithography | 10 | 21% |
| 4 | MATROLOGY FOR LITHOGRAPHY The concept of CD in metrology, Grating optical diffractometry or scatterometry | 10 | 20% |
| 5 | WHAT IS MOST SUITABLE TECHNIQUE FOR LITHOGRAPHY? Technique Correlation, Technique Calibration, Process Development, Evaluation of Morphological Damage Generated by the Primary Electron Beam from CD-SEM | 8 | 17% |

Suggested Specification table with Marks (Theory):

| Distribution of Theory Marks | | | | | | | | | |
|------------------------------|---------|---------|---------|---------|---------|--|--|--|--|
| R Level | U Level | A Level | N Level | E Level | C Level | | | | |
| 15 | 33 | 15 | 7 | - | - | | | | |

Legends: R: Remembrance; U: Understanding; A: Application, N: Analyze and E: Evaluate C: Create and above Levels (Revised Bloom's Taxonomy)

Note: This specification table shall be treated as a general guideline for students and teachers. The actual distribution of marks in the question paper may vary slightly from above table

Reference Books:

- **1. NANOLITHOGRAPHY** M Feldman (Editor), ISBN: 9780081014042, Elsevier, Imprint: Woodhead Publishing, 13th November 2013.
- 2. MICROFABRICATION AND NANOMANUFACTURING Mark J. Jackson, Taylor & Francis, 2006
- **3. SPRINGER HANDBOOK OF NANOTECHNOLOGY** Bharat Bhushan (Editors), DOI:10.1007/978-3-642-02525-9, Springer-Verlag Berlin Heidelberg, 2010.
- 4. NANOLITHOGRAPHY Stefan Landis (Editor), ISBN: 978-1-84821-211-4, Wiley-ISTE, 2011

Course Outcome:

After learning the course the students should be able to:

- 1. To notify the learner about the various type of lithography technique.
- 2. To understand about fabrication of devices.
- 3. To understand about which lithography technique is best for devices.

List of Open Source Software/learning website:

http://www.intechopen.com/books/lithography

ACTIVE LEARNING ASSIGNMENTS: Preparation of power-point slides, which include videos, animations, pictures, graphics for better understanding theory and practical work – The faculty will allocate chapters/ parts of chapters to groups of students so that the entire syllabus to be covered. The power-point slides should be put up on the web-site of the College/ Institute, along with the names of the students of the group, the name of the faculty, Department and College on the first slide. The best three works should submit to GTU.